

HS1A THRU **HS1M**

1.0 AMP. High Efficient Surface Mount Rectifiers



Voltage Range 50 to 1000 Volts Current 1.0 Ampere

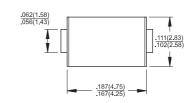
Features

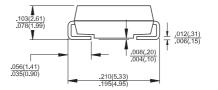
- ♦ Glass passivated junction chip.
- ♦ For surface mounted application
- ♦ Low forward voltage drop
- Low profile package
- Built-in stain relief, ideal for automatic placement
- → High temperature soldering: 260°C/10 seconds at terminals
- Plastic material used carries Underwriters Laboratory Classification 94V-O

Mechanical Data

- ♦ Cases: Molded plastic
- → Terminals: Solder plated→ Polarity: Indicated by cathode band
- ♦ Packing: 12mm tape per E1A STD RS-481
- ♦ Weight: 0.064 gram

SMA/DO-214AC





Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

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Type Number	Symbol	HS 1A	HS 1B	HS 1D	HS 1F	HS 1G	HS 1J	HS 1K	HS 1M	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Rectified Current See Fig.2	I _(AV)	1.0								Α
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	30								Α
Maximum Instantaneous Forward Voltage @ 1.0A	V _F	1.0 1.3 1.7						V		
Maximum DC Reverse Current @ $T_A = 25^{\circ}C$ at Rated DC Blocking Voltage @ $T_A = 100^{\circ}C$	I _R	5.0 100								uA uA
Maximum Reverse Recovery Time (Note 1)	Trr	50 75						nS		
Typical Junction Capacitance (Note 2)	Cj	20 15							pF	
Operating Temperature Range	TJ	-55 to +150							$^{\circ}$	
Storage Temperature Range	Tstg	-55 to +150							$^{\circ}$	

Notes: 1. Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A

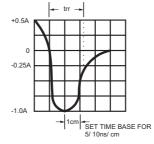
2. Measured at 1 MHz and Applied VR=4.0 Volts



RATINGS AND CHARACTERISTIC CURVES (HS1A THRU HS1M)

FIG.1- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

NONINDUCTIVE NONINDUCTIVE (-) DUT (+) 50Vdc PULSE GENERATOR (approx) (NOTE 2) 10 OSCILLOSCOPE **≸**NON (+) (NOTE 1) INDUCTIVE NOTES: 1. Rise Time=7ns max. Input Impedance= 1 megohm 22pf
2. Rise Time=10ns max. Sourse Impedance=



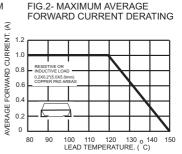
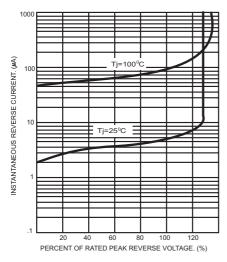


FIG.3- TYPICAL REVERSE CHARACTERISTICS

50 ohms



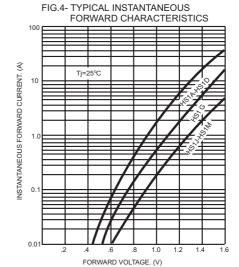


FIG.5- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

